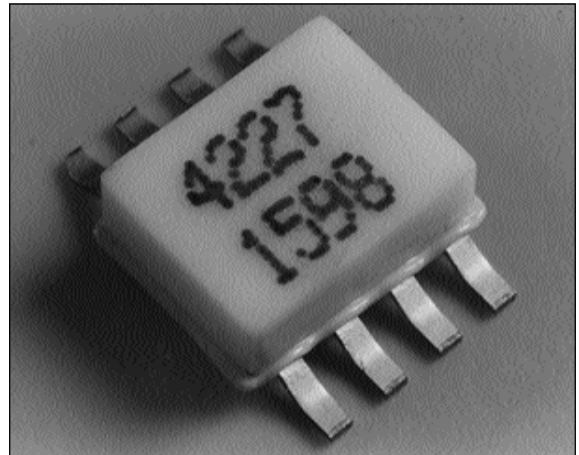


# GaAs MMIC SPDT Terminated Switch, DC - 6GHz



## Features

- Broadband performance
- High isolation; 32dB typ at 3GHz
- Low insertion loss; 1.0dB typ at 3GHz
- Ultra low DC power consumption
- Fast switching speed; 3ns typical
- SO8 surface mount ceramic package

## Description

The P35-4227-C06-200 is a high performance Gallium Arsenide single pole double throw broadband RF switch. It is suitable for use in broadband communications and instrumentation applications. A 50 $\Omega$  termination is presented at the isolated output of the switch. The switch is controlled by the application of complimentary 0V/-5V or 0/-8V signals to the control lines in accordance with the truth table below.

This die is fabricated using MOCs 0.5 $\mu$ m gate length MESFET process (S20) and is fully protected using Silicon Nitride passivation for excellent performance and reliability. This device is packaged in a SO8 sized surface mount ceramic package.

## Electrical Performance

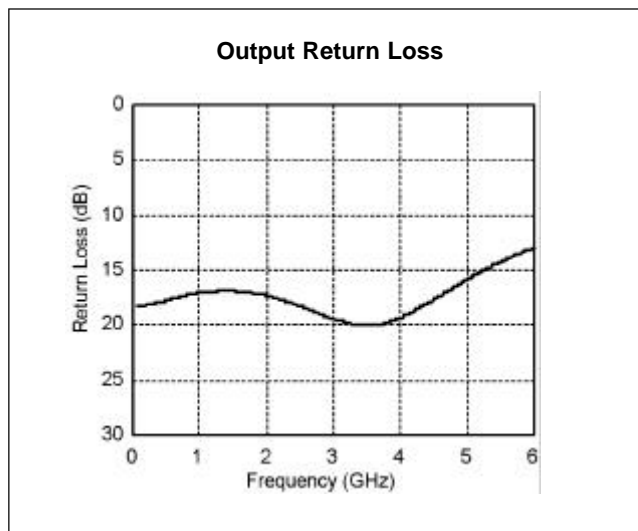
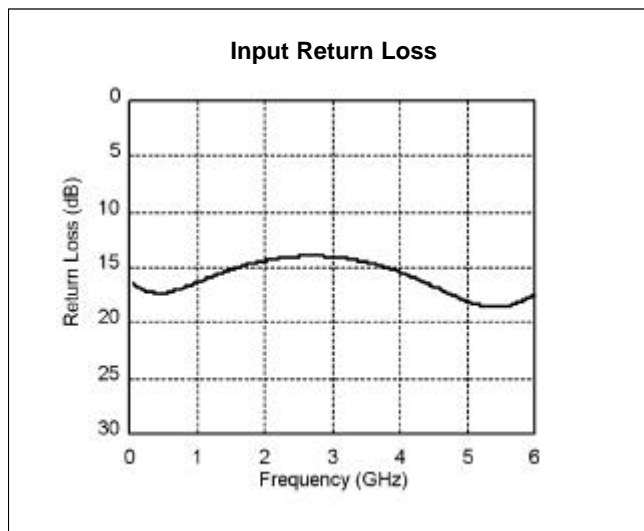
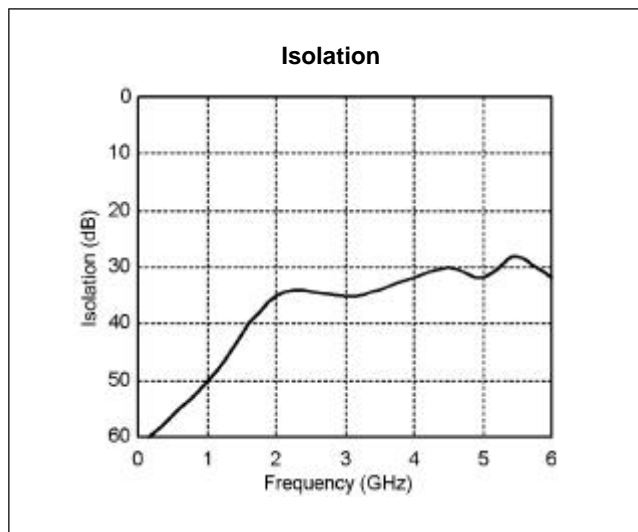
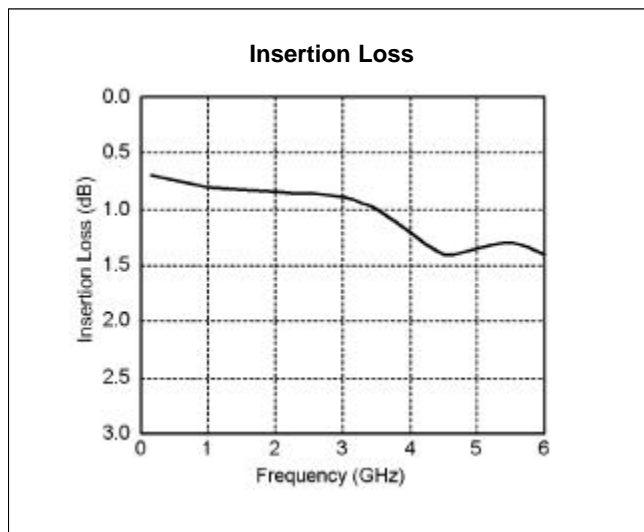
Ambient temperature = 22 $\pm$ 3 $^{\circ}$ C , Z<sub>O</sub> = 50 $\Omega$ , Control voltages = 0V/-5V unless otherwise stated

Parameter	Conditions	Min	Typ	Max	Units
Insertion Loss	DC - 3GHz	-	1.0	1.5	dB
	3 - 6GHz	-	1.5	2.0	dB
Isolation	DC - 3GHz	30	33	-	dB
	3 - 6GHz	25	28	-	dB
Input Return Loss <sup>1</sup>	DC - 6GHz	10	12	-	dB
Output Return Loss <sup>1</sup>	DC - 6GHz	10	12	-	dB
1dB power compression point <sup>2</sup>	0/-5V Control; 50MHz	-	20	-	dBm
	0/-5V Control; 2GHz	-	26	-	dBm
Switching Speed	50% Control to 10%90%RF	-	3	8	ns

## Notes

1. Return Loss measured in low loss switch state.
2. Input power at which insertion loss compresses by 1dB.

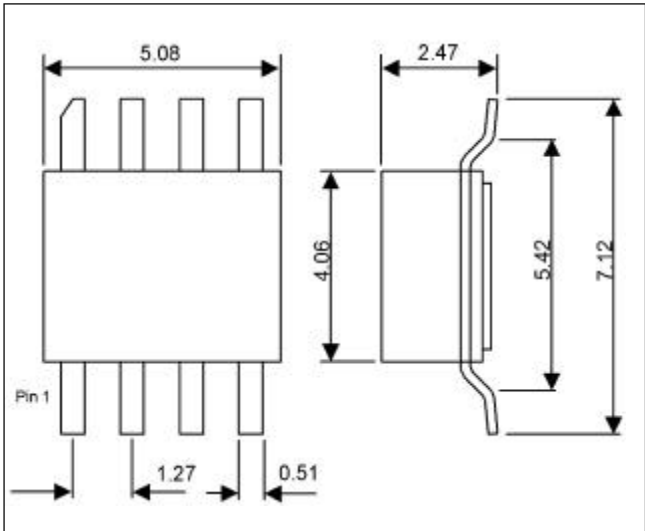
## Typical Performance at 22°C



## Absolute Maximum Ratings

Max control voltage	-8V
Max I/P power	+30 dBm
Operating temperature	-40°C to +85°C
Storage temperature	-65°C to +150°C

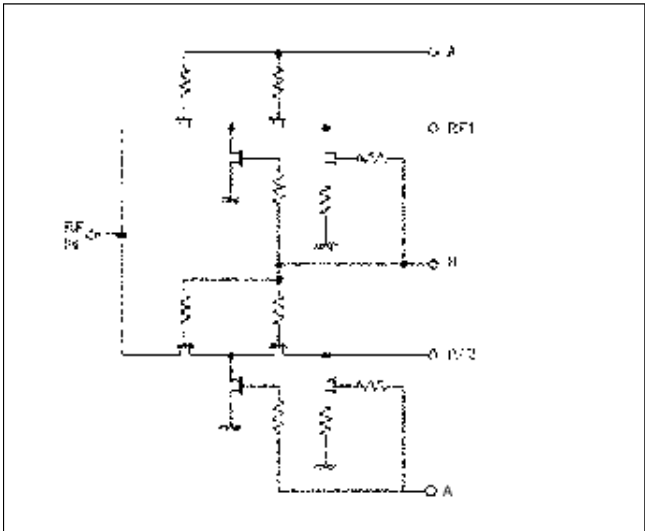
Package Outline



Pin Details

Pin	Function
1	Ground
2	RF IN
3	Ground
4	Ground
5	RF1
6	Control A
7	Control B
8	RF2

Electrical Schematic



Switching Truth Table

A	B	RF IN-RF1	RF IN-RF 2
0V	-5V	Low loss	Isolated
-5V	0V	Isolated	Low loss

**Ordering Information: P35-4227-C06-200**

463/SM/00128/200 Iss 2/2

The data and product specifications are subject to change without notice. These devices should not be used for device qualification and production without prior notice.



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